

Electronic Circuits I – Laboratory 01

Diode

#	Student ID	Student Name	Grade (10)	Instructor signature
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Objective

The objective of this exercise is to examine the operation of the basic switching diode and to plot its characteristic curve.

Theory Overview

The basic diode is an asymmetric non-linear device. That is, its current-voltage characteristic is not a straight line and it is sensitive to the polarity of an applied voltage or current. When placed in forward bias (i.e. positive polarity from anode to cathode), the diode will behave much like a shorted switch and allow current flow. When reversed biased the diode will behave much like an open switch, allowing little current flow. Unlike switch, a silicon diode will exhibit an approximate .7 volt drop when forward biased. The precise voltage value will depend on the semiconductor material used. This volt drop is sometimes referred to as the knee voltage as the resulting I-V curve looks something like a bent knee.

The effective instantaneous resistance of the diode above the turn-on threshold is very small, perhaps a few ohms or less, and is often ignored. Analysis of diode circuits typically proceeds by determining if the diode is forward or reversed biased, substituting the appropriate approximation for the device, and then solving for desired circuit parameters using typical analysis techniques. For example, when forward biased, a silicon diode can be thought of as a fixed .7 volt drop, and then KVL and KCL can be applied as needed

Schematic

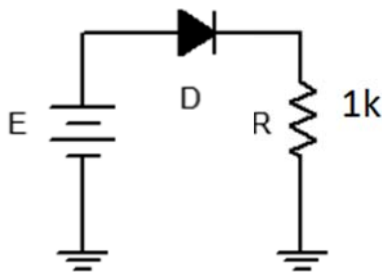


Figure 1

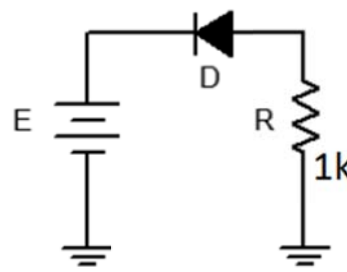


Figure 2

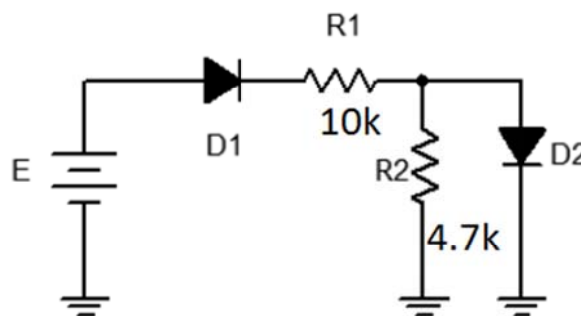


Figure 3

Procedure

Forward Curve

For any positive value of E , the diode should be forward biased. Once E exceeds the knee voltage, all of E (minus approximately .7 volts) drops across R . Thus, as E increases, so does the diode current.

Build the circuit of Figure 1 using $R = 1 \text{ k}\Omega$. Set E to 0 volts and measure both the diode's voltage and current and record the results in Table 1 Repeat this process for the remaining source voltages listed.

From the data collected in Table 1, plot the current versus voltage characteristic of the forward biased diode. Make sure V_D is the horizontal axis with I_D on the vertical

Reverse Curve

For circuit of Figure 2, For any positive value of E , the diode should be reversed biased. In this case, the diode should always behave like an open switch and thus no current should flow. If no current flows, the voltage across R should be zero, and thus the diode voltage should be equal to the applied source voltage

Build the circuit of Figure 1.2 using $R = 1 \text{ k}\Omega$. Set E to 0 volts and measure both the diode's voltage and current and record the results in Table 2. Repeat this process for the remaining source voltages listed.

From the data collected in Table 2, plot the current versus voltage characteristic of the reverse biased diode. Make sure V_D is the horizontal axis with I_D on the vertical.

Practical Analysis

Consider the circuit of Figure 3 using $E = 12$ volts, $R_1 = 10 \text{ k}\Omega$ and $R_2 = 4.7 \text{ k}\Omega$. Analyze the circuit using the ideal .7 volt forward drop approximation and determine the voltages across the two resistors. Record the results in the first two columns of the first row (Variation 1) of Table 3.

Build the circuit of Figure 3 using $E = 12$ volts, $R_1 = 10 \text{ k}\Omega$ and $R_2 = 4.7 \text{ k}\Omega$. Measure the voltages across the two resistors. Record the results in columns three and four of the first row (Variation 1) of Table 3. Also compute and record the percent deviations in columns four and five.

Change the applied volatæg (E) and record calculate, measured voltage different five times

Results and data analysis

Table 1

E (volts)	V_d	I_d
0		
.5		
1		
2		
4		
6		
8		
10		

Table 2

E (volts)	V_d	I_d
0		
1		
2		
4		
6		
8		
10		

Table 03

E (volts)	V_d (calculated)	I_d (calculated)	V_d Measured)	I_d (Measured)	% Dev V_{R1}	% Dev V_{R2}
12						
10						
8						
6						
4						
2						

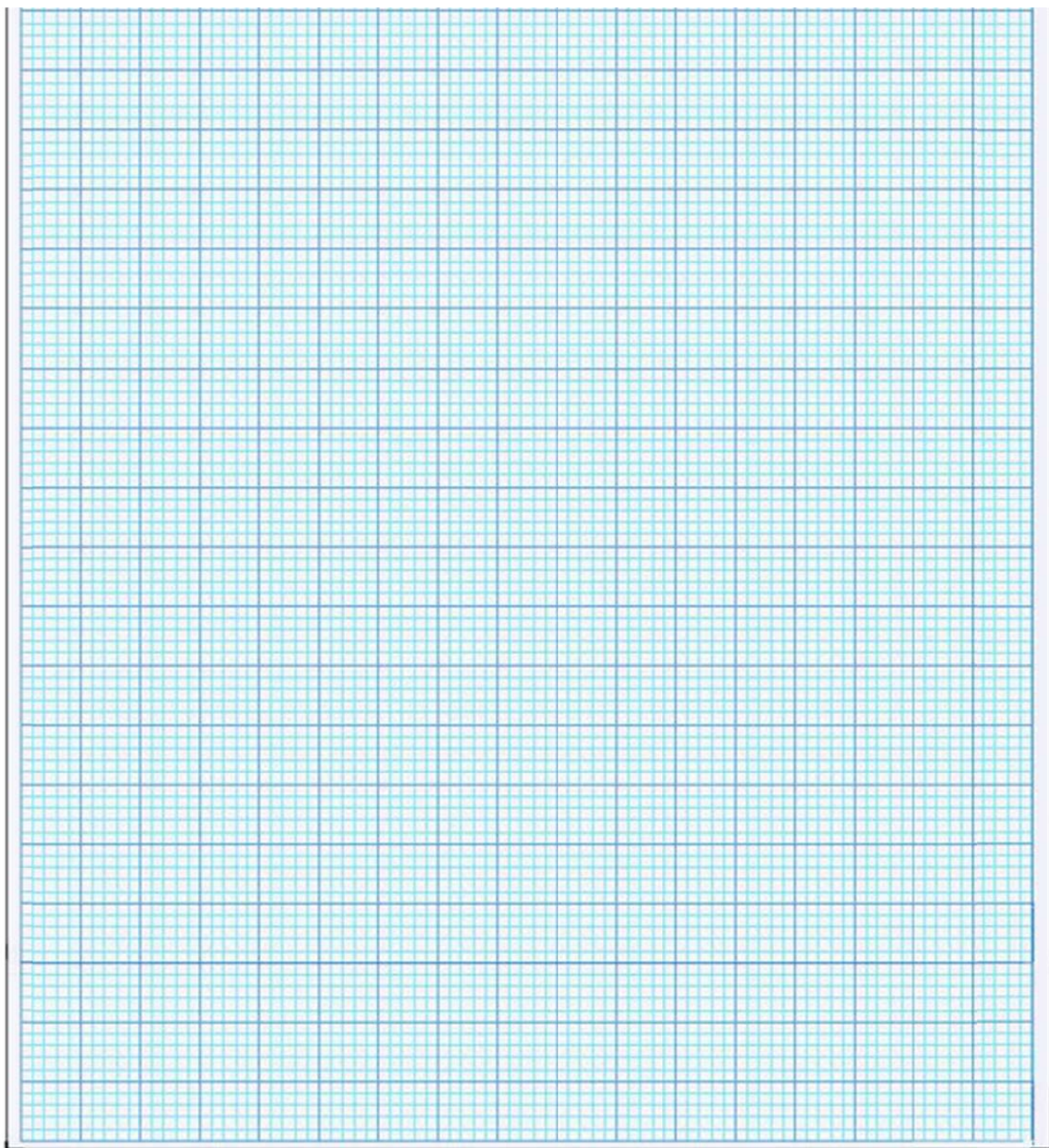


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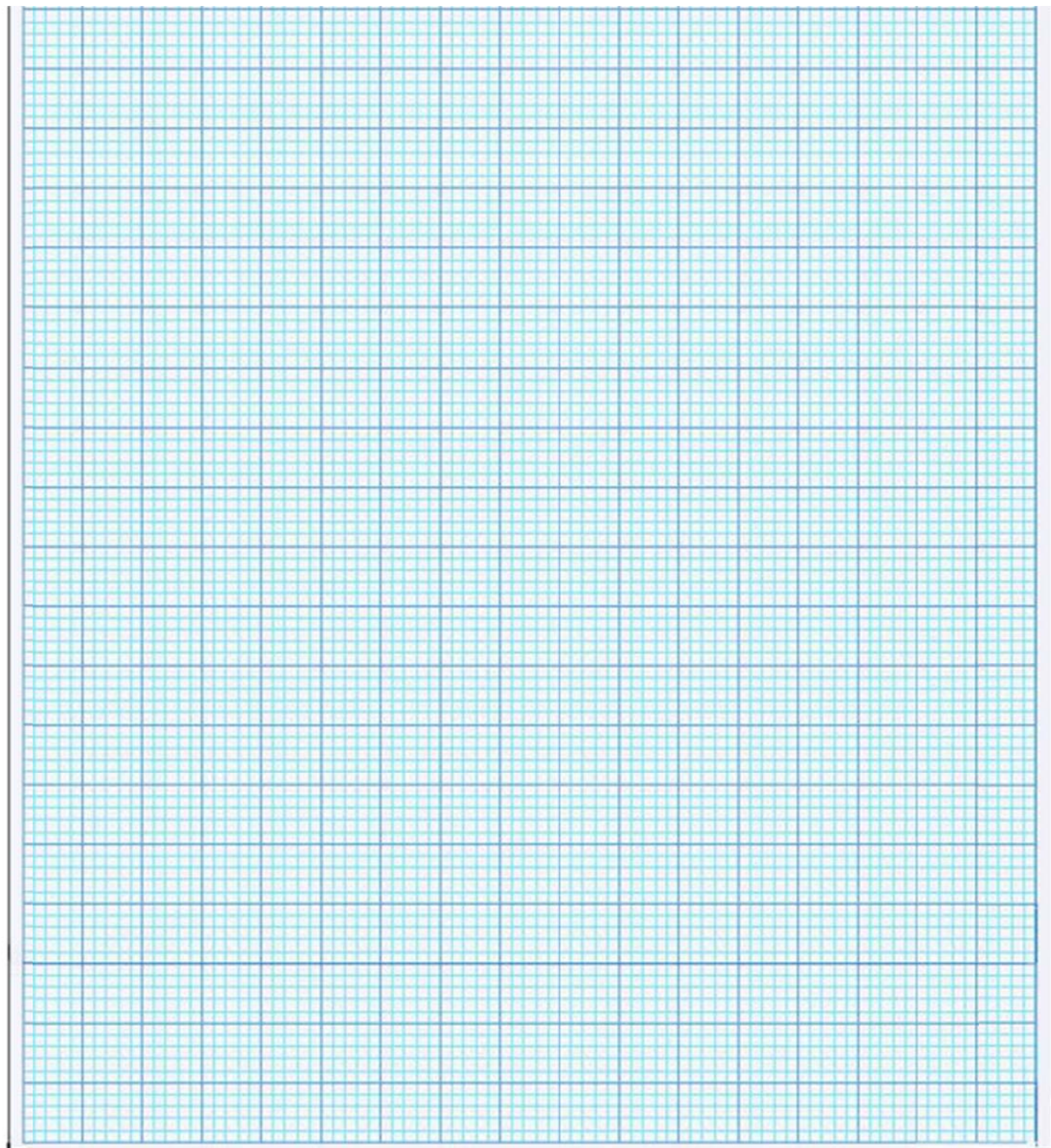


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3. The dynamic resistance, of a diode may be approximated by taking the differences between adjacent current-voltage readings. That is, $r_{diode} = \Delta V_{diode} / \Delta I_{diode}$. What are the smallest and largest resistances using Table 1 (show work)? Based on this, what would a plot of instantaneous diode resistance versus diode current look like?

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